P3HT/POSS 합성 활성층을 이용한 OTFT 소자 제작 및 특성 연구

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Study on fabrication and characteristic of OTFT with a P3HT/POSS active layer

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Abstract: To improved the conjugation between SiO_2 and P3HT active layer, P3HT/POSS conjugated polymers were synthesised and used as the active layers of organic TFT's. We achieved the field-effect mobilities in the saturation region $\sim 1.19 \times 10^{-3}$ [cm/v·sec] and on/off ratio $\sim 2.51 \times 10^2$. These values are higher than ones of the P3HT-based OTFTs. The results also demonstrated the off-current decrease.

Key Words: P3HT, POSS, OTFT, Off-current